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Kind regards,

Team Nexperia



PDTB123TT

PNP 500 mA, 50 V resistor-equipped transistor; R1 = 2.2 k Ω , R2 = open

Rev. 4 — 8 November 2010

Product data sheet

1. Product profile

1.1 General description

500 mA PNP Resistor-Equipped Transistor (RET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

NPN complement: PDTD123TT.

1.2 Features and benefits

- 500 mA output current capability
- Built-in bias resistor
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

1.3 Applications

- Digital application in automotive and industrial segments
- Control of IC inputs

- Cost-saving alternative for BC807 series in digital applications
- Switching loads

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	-50	V
Io	output current		-	-	-500	mA
R1	bias resistor 1 (input)		1.54	2.2	2.86	kΩ



PNP 500 mA resistor-equipped transistor; R1 = 2.2 k Ω , R2 = open

2. Pinning information

Table 2. Pinning

Table 2.	ı ıııılıng		
Pin	Description	Simplified outline	Graphic symbol
1	input (base)		
2	GND (emitter)	[3]	3
3	output (collector)	1 2 006aaa144	1 R1 2 sym009

3. Ordering information

Table 3. Ordering information

Type number	Package			
	Name	Description	Version	
PDTB123TT	-	plastic surface-mounted package; 3 leads	SOT23	

4. Marking

Table 4. Marking codes

Type number	Marking code ^[1]
PDTB123TT	*1U

- [1] * = -: made in Hong Kong
 - * = p: made in Hong Kong
 - * = t: made in Malaysia
 - * = W: made in China

PNP 500 mA resistor-equipped transistor; R1 = 2.2 k Ω , R2 = open

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	-50	V
V_{CEO}	collector-emitter voltage	open base	-	-50	V
V_{EBO}	emitter-base voltage	open collector	-	- 5	V
VI	input voltage				
	positive		-	+5	V
	negative		-	-12	V
Io	output current		-	-500	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	<u>[1]</u> -	250	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	<u>[1]</u> _	-	500	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

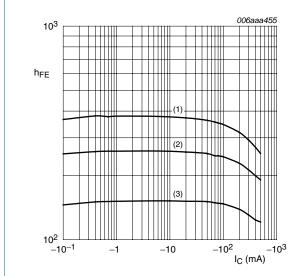
PNP 500 mA resistor-equipped transistor; R1 = 2.2 k Ω , R2 = open

7. Characteristics

Table 7. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

· amb = -	,					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I_{CBO}	collector-base	$V_{CB} = -40 \text{ V}; I_E = 0 \text{ A}$	-	-	-100	nA
	cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$	-	-	-100	nA
I _{CEO}	collector-emitter cut-off current	$V_{CE} = -50 \text{ V}; I_B = 0 \text{ A}$	-	-	-0.5	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$	-	-	-100	nA
h _{FE}	DC current gain	$V_{CE} = -5 \text{ V};$ $I_{C} = -50 \text{ mA}$	100	250	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -50 \text{ mA};$ $I_B = -2.5 \text{ mA}$	-	-	-0.3	V
R1	bias resistor 1 (input)		1.54	2.2	2.86	kΩ
C _c	collector capacitance	$V_{CB} = -10 \text{ V};$ $I_E = i_e = 0 \text{ A};$ $f = 100 \text{ MHz}$	-	11	-	pF



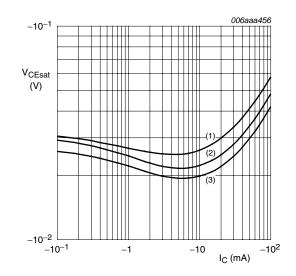


⁽¹⁾ $T_{amb} = 100 \, ^{\circ}C$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3) $T_{amb} = -40 \, ^{\circ}C$

Fig 1. DC current gain as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 20$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3) $T_{amb} = -40 \, ^{\circ}C$

Fig 2. Collector-emitter saturation voltage as a function of collector current; typical values

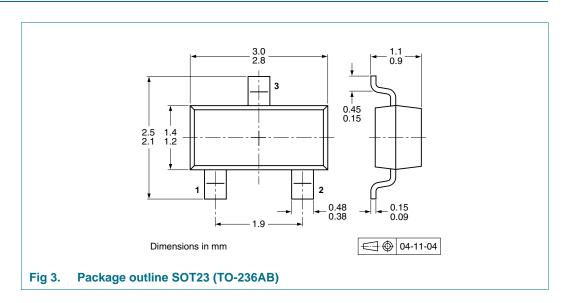
PNP 500 mA resistor-equipped transistor; R1 = 2.2 k Ω , R2 = open

8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



10. Packing information

Table 8. Packing methods

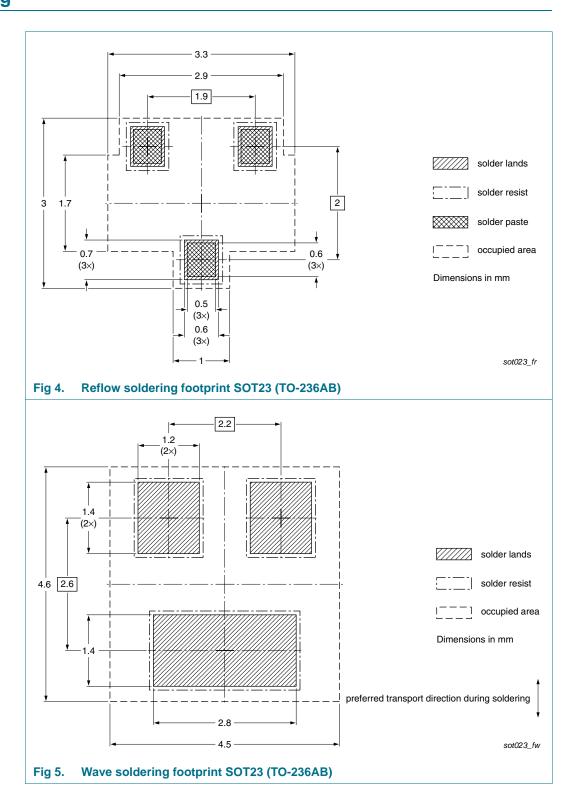
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity	
			3000	10000
PDTB123TT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235

^[1] For further information and the availability of packing methods, see Section 14.

PNP 500 mA resistor-equipped transistor; R1 = 2.2 k Ω , R2 = open

11. Soldering



PNP 500 mA resistor-equipped transistor; R1 = 2.2 kΩ, R2 = open

12. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTB123TT v.4	20101108	Product data sheet	-	PDTB123T_SER_3
Modifications:	 Type numbers 	PDTB123TK and PDTB12	23TS deleted.	
	 Table 7 "Chara 	acteristics": unit for V _{CEsat} o	changed from mV to V	
	 Section 8 "Tes 	t information": added.		
	 Section 11 "So 	ldering": added.		
	 Section 13 "Le 	gal information": updated.		
PDTB123T_SER_3	20091116	Product data sheet	-	PDTB123T_SER_2
PDTB123T_SER_2	20050804	Product data sheet	-	PDTB123TK_1
PDTB123TK_1	20050519	Product data sheet	-	-

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13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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PDTB123TT

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PDTB123TT **NXP Semiconductors**

PNP 500 mA resistor-equipped transistor; R1 = 2.2 k Ω , R2 = open

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

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14. Contact information

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PNP 500 mA resistor-equipped transistor; R1 = 2.2 k Ω , R2 = open

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